## DATA SHEET



# MOS FIELD EFFECT TRANSISTOR $\mu$ PA1900

### N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### DESCRIPTION

The  $\mu\text{PA1900}$  is a switching device which can be driven directly by a 2.5 V power source.

The  $\mu$ PA1900 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### FEATURES

- Can be driven by a 2.5 V power source
- Low on-state resistance  $R_{DS(on)1} = 35 \text{ m}\Omega \text{ MAX.}$  (Vgs = 4.5 V, ID = 3.0 A)  $R_{DS(on)2} = 38 \text{ m}\Omega \text{ MAX.}$  (Vgs = 4.0 V, ID = 3.0 A)  $R_{DS(on)3} = 45 \text{ m}\Omega \text{ MAX.}$  (Vgs = 2.5 V, ID = 3.0 A)

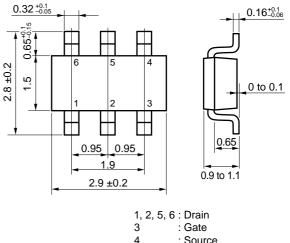
### **ORDERING INFORMATION**

PART NUMBER	PACKAGE			
μΡΑ1900ΤΕ	6-pin Mini Mold (Thin Type)			

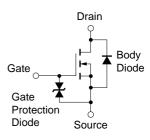
### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

Drain to Source Voltage	Vdss	20	V
Gate to Source Voltage	Vgss	±12	V
Drain Current (DC)	D(DC)	±5.5	А
Drain Current (pulse) Note1	D(pulse)	±22	А
Total Power Dissipation	<b>P</b> T1	0.2	W
Total Power Dissipation Note2	Рт2	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

# PACKAGE DRAWING (Unit : mm)



#### EQUIVALENT CIRCUIT



Marking: TG

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

- **2.** Mounted on FR-4 Board,  $t \le 5$  sec.
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

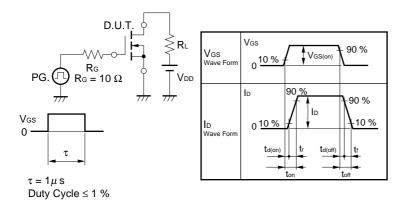
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### ★ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

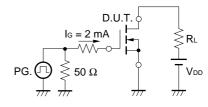
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 20 V, V_{GS} = 0 V$			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 12 V$ , $V_{DS} = 0 V$			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = 10 V, I_{D} = 1 mA$	0.5	0.93	1.5	V
Forward Transfer Admittance	y <sub>fs</sub>	$V_{DS} = 10 V, I_{D} = 3.0 A$	3	9.2		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 4.5 V, I_{D} = 3.0 A$		28	35	mΩ
	RDS(on)2	$V_{GS} = 4.0 V$ , $I_{D} = 3.0 A$		29	38	mΩ
	RDS(on)3	Vgs = 2.5 V, Id = 3.0 A		37	45	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		595		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		222		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		133		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 10 V		61		ns
Rise Time	tr	ID = 3.0 A		172		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = 4.0 V$		220		ns
Fall Time	tr	R <sub>G</sub> = 10 Ω		293		ns
Total Gate Charge	QG	V <sub>DS</sub> = 16 V		6.7		nC
Gate to Source Charge	QGS	ID = 5.5 A		1.2		nC
Gate to Drain Charge	Qgd	V <sub>GS</sub> = 4.0 V		3.1		nC
Diode Forward Voltage	VF(S-D)	IF = 5.5 A, VGS = 0 V		0.87		V

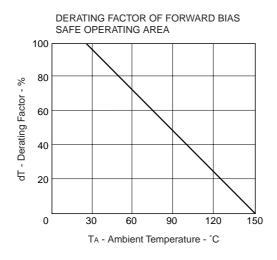
### **TEST CIRCUIT 1 SWITCHING TIME**

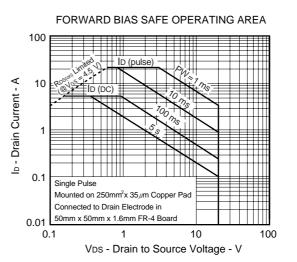


TEST CIRCUIT 2 GATE CHARGE

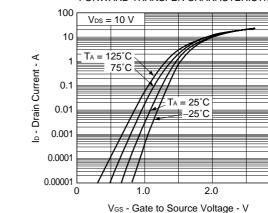


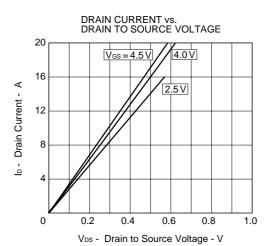
### **★** TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

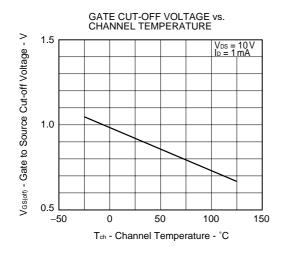






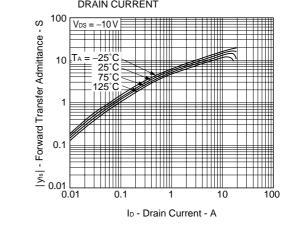




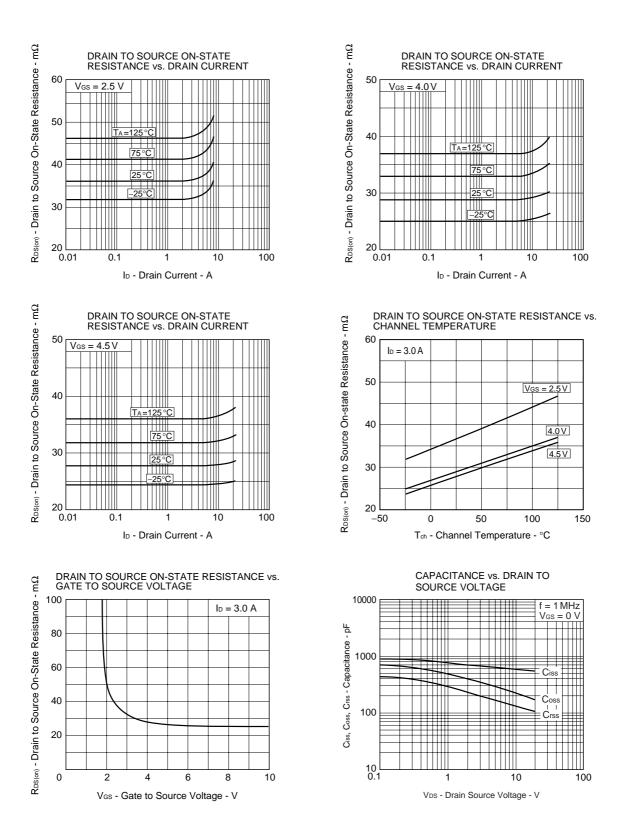


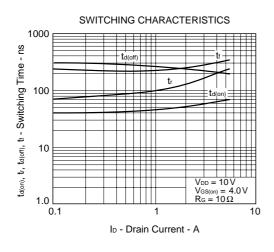
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

3.0

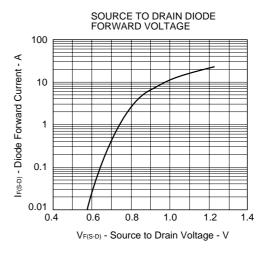


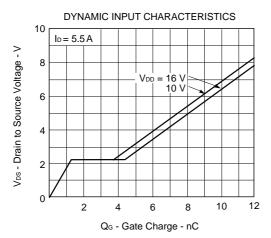
Data Sheet D13809EJ1V0DS00

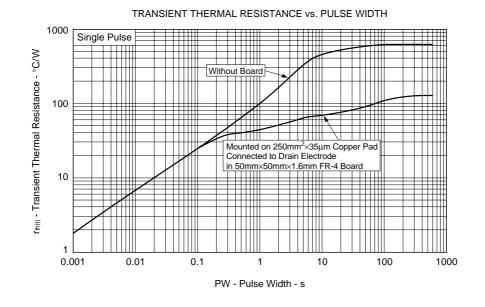




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